

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	181281	"438"/\$.cccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 11:45
L4	23	L3 and semiconductor and thermopile near4 (detector or sensor) and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 12:50
L5	23	(US-20010040248-\$ or US-20030025174-\$ or US-20030148620-\$ or US-20040018746-\$ or US-20040053435-\$ or US-20040058488-\$ or US-20040113080-\$ or US-20040121494-\$ or US-20040253759-\$ or US-20050037617-\$ or US-20050064619-\$).did. or (US-5059543-\$ or US-5100479-\$ or US-5288649-\$ or US-6372656-\$ or US-6551853-\$ or US-6597051-\$ or US-6617175-\$ or US-6787387-\$ or US-6821795-\$ or US-6828172-\$ or US-6890834-\$ or US-6965107-\$). did.	US-PGPUB; USPAT	OR	ON	2006/02/15 12:43
L6	23	L5 and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:03
L7	9933	257/440,460,323,293,417,431,436, 440,458,464,465,466,467,470,930, E21.252,E27.008,E27.144,E29.324, E31.093.CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L8	4	L7 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02

L9	337910	"257"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L10	28966	"374"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L11	142447	"324"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L12	223331	"73"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L13	9	L3 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L14	4	L9 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L15	5	L10 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L16	0	L11 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02

L17	1	L12 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:27
L18	17	L13 or L14 or L15 or L16 or L17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:02
L19	17	L18 and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:04
L20	17	(US-20040121494-\$ or US-20040113080-\$ or US-20040018746-\$ or US-20040058488-\$ or US-20040253759-\$ or US-20050037617-\$).did. or (US-6821795-\$ or US-6617175-\$ or US-6384384-\$ or US-5367167-\$ or US-5288649-\$ or US-6480103-\$ or US-5180226-\$ or US-3777568-\$ or US-4558342-\$ or US-5782974-\$ or US-5549756-\$).did.	US-PGPUB; USPAT	OR	ON	2006/02/15 13:04
L21	2	"L220" and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:12
L22	17	L20 and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:05
L23	7	L20 and (infrared near2 radiation) same (source or emitter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:11

L24	2	("5782974").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/15 13:11
L25	1	L24 and ((infrared near2 radiation) or infrared)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:13
L26	1	L25 and infrared same (lamp or source)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:14
L27	1	L24 and infrared same (lamp or source)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:14
L28	52	semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter)) and infrared same (source or lamp or emitter or emit\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:29
L29	53	semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter)) and infrared same (source or lamp or emitter or emit\$4 or beam)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:29

L30	53	(US-20040039298-\$ or US-20040039297-\$ or US-20030139687-\$ or US-20020049389-\$ or US-20040121494-\$ or US-20040113080-\$ or US-20040018746-\$ or US-20040058488-\$ or US-20050257828-\$ or US-20050023858-\$ or US-20030102688-\$ or US-20050238538-\$ or US-20040093167-\$ or US-20040253759-\$ or US-20060022139-\$ or US-20010013831-\$ or US-20030139682-\$ or US-20060016995-\$ or US-20050037617-\$ or US-20020196131-\$ or US-20040132168-\$ or US-20040106343-\$ or US-20010045547-\$ or US-20050030628-\$).did. or (US-6544193-\$ or US-6821795-\$ or US-6617175-\$ or US-6783167-\$ or US-6485081-\$ or US-6931328-\$ or US-6335478-\$ or US-6384384-\$ or US-6046398-\$ or US-6995371-\$ or US-6838669-\$ or US-6222454-\$ or US-6652468-\$ or US-6540690-\$ or US-5367167-\$ or US-5288649-\$ or US-6621411-\$ or US-6480103-\$ or US-5180226-\$ or US-6800155-\$ or US-5782974-\$ or US-5549756-\$ or US-6444474-\$ or US-4816294-\$ or US-5721430-\$ or US-5650624-\$). did. or (US-20040113080-\$ or US-20040018746-\$ or US-20040058488-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2006/02/15 13:29
L31	20	L30 and infrared near2 radiation and infrared same (lamp or beam)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 13:35
L32	11	L30 and infrared near2 radiation and infrared same (lamp or beam) same thermopile	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 17:04
L33	2	(US-20040106343-\$).did. or (US-6335478-\$).did.	US-PGPUB; USPAT	OR	ON	2006/02/15 14:15

L35	1	I33 and (lamp or mirror)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 19:24
L36	64	semiconductor and thermopile near detector and infrared near2 radiation and infrared same (source or beam)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 16:34
L37	15	((("5782974") or ("20030148620") or ("4527896") or ("5594248") or ("5367167") or ("6828172") or ("6045257") or ("20030111605") or ("4527896"))).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/15 17:47
L38	3	I37 and infrared same (lamp or source)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 19:23
L40	4	L37 and mirror	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 17:49
L41	4	L37 and mirror and infrared	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 19:35
L42	0	I37 and infrared same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 19:23
L43	16	I31 and lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 19:25

L44	0	l41 and beam	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 19:35
S64	175156	"438"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:07
S65	323883	"257"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:08
S66	28757	"374"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:08
S67	140536	"324"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:09
S68	221076	"73"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:09
S69	9	S64 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:28
S70	4	S65 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:29

S71	5	S66 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:18
S72	0	S67 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:18
S73	1	S68 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:32
S74	4014252	S69 or S70 or S71 or S72 or "70"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:19
S75	17	S69 or S70 or S71 or S72 or S73	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:19
S76	17	(US-20050037617-\$ or US-20040253759-\$ or US-20040121494-\$ or US-20040113080-\$ or US-20040058488-\$ or US-20040018746-\$).did. or (US-6821795-\$ or US-6617175-\$ or US-6480103-\$ or US-6384384-\$ or US-5782974-\$ or US-5549756-\$ or US-5367167-\$ or US-5288649-\$ or US-5180226-\$ or US-4558342-\$ or US-3777568-\$).did.	US-PGPUB; USPAT	OR	ON	2005/09/01 15:26
S77	8	(US-20030111605-\$ or US-20030148620-\$).did. or (US-6828172-\$ or US-6045257-\$ or US-5367167-\$ or US-5404125-\$ or US-5782974-\$ or US-5594248-\$). did.	US-PGPUB; USPAT	OR	ON	2005/09/01 15:29

S78	13	S64 and semiconductor and thermopile near detector and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:30
S79	2	S77 and semiconductor and thermopile near detector and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:30
S80	22	S64 and semiconductor and thermopile near4 (detector or sensor) and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:47
S81	8	S77 and semiconductor and thermopile near4 (detector or sensor) and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:39
S82	8	S77 and thermopile near4 (detector or sensor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:46
S83	6	S77 and thermopile and (detector or sensor) and infrared and (target or material or sample)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 16:24
S84	8	S77 and thermopile and (detector or sensor) and infrared	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:53
S85	1	S83 and (controller or computer\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:00
S86	1	(US-5782974-\$).did.	USPAT	OR	ON	2005/09/01 17:00

S87	6	S84 and (gas or computer or solid or liquid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:23
S89	1	S86 and (gas or computer or solid or liquid or fluid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:14
S90	3	S84 and (fluid or liquid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:24
S91	1	S86 and (fluid or liquid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:24
S92	0	438/7,14,54,200,46,343,758,989	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:48
S93	5069	438/7,14,54,200,46,343,758,989. CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:49
S94	8	S93 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:51
S95	9558	257/440,460,323,293,417,431,436,440,458,464,465,466,467,470,930,E21.252,E27.008,E27.144,E29.324,E31.093.CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:51

S97	9558	257/440,460,323,293,417,431,436, 440,458,464,465,466,467,470,930, E21.252,E27.008,E27.144,E29.324, E31.093.CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:49
S98	4	S97 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 16:33
S99	1	(US-5782974-\$).did.	USPAT	OR	ON	2005/09/01 21:51
S10 0	1	S99 and (plasma or gas or liquid or fluid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:56